App. Ser. No. 10/656,812

Atty. Dkt. No.: 038724.52699US

PATENT

IN THE CLAIMS:

Entry of the following amendments in order to place the claims into condition for allowance is respectfully requested:

1. (previously presented) A process for the laser welding of nonferrous metals, consisting essentially of:

providing one or more laser diodes as a laser beam source;

guiding at least one focused laser beam to the workpiece surface to be machined; and

flowing a process gas against the workpiece surface, wherein the process gas comprises

- 100% by volume carbon dioxide, or
- a binary gas mixture of carbon dioxide and argon, or
- a binary gas mixture of carbon dioxide and nitrogen, or
- a ternary gas mixture of carbon dioxide, argon and nitrogen.
- 2. (currently amended) A <u>The</u> process according to Claim 1, wherein the process gas is one of said binary or ternary gas mixtures, and the process gas contains between about 15% and about 90% by volume of carbon dioxide.
- 3. (currently amended) A <u>The</u> process according to claim 1, wherein the process gas is one of said binary or ternary gas mixtures, and the process gas contains between about 45% and about 85% by volume of carbon dioxide.

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4. (currently amended) A The process according to claim 1, wherein the

process gas is one of said binary or ternary gas mixtures, and the process gas

contains between about 55% and about 80% by volume of carbon dioxide.

5-8. (canceled)

9. (currently amended) A The process according to claim 1, wherein the

process gas is one of said binary or ternary gas mixtures, the process gas further

comprises comprising oxygen, and the process gas contains up to 50% by volume

of carbon dioxide.

10-11 (canceled)

12. (currently amended) A The process according to Claim 1, wherein the

one or more laser diodes produce a wavelength of between about 700 nm and

about 1,300 nm.

13. (currently amended) A The process according to claim 1, wherein the

one or more laser diodes produce a wavelength of between about 800 nm to about

1000 nm.

14. (canceled)

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